Product data sheet

1. General description

The 74LV00A is a quad 2-input NAND gate.

Inputs are overvoltage tolerant. This feature allows the use of these devices as translators in mixed voltage environments.

Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times.

This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 2.0 V to 5.5 V
- Maximum t_{pd} of 9 ns at 5 V
- Typical V_{OL(p)} < 0.8 V at V_{CC} = 3.3 V, T_{amb} = 25 °C
- Typical $V_{OH(v)}$ > 2.3 V at V_{CC} = 3.3 V, T_{amb} = 25 °C
- Supports mixed-mode voltage operation on all ports
- I_{OFF} circuitry provides partial Power-down mode operation
- Latch-up performance exceeds 250 mA per JESD 78 Class II
- ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 3A exceeds 4000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

3. Ordering information

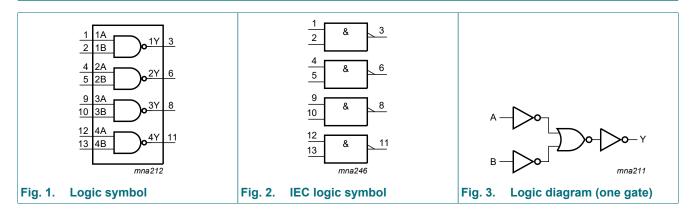
Table 1. Ordering information

| Type number | Package | | | | | | | |
|-------------|-------------------|---------|--|----------|--|--|--|--|
| | Temperature range | Name | Description | Version | | | | |
| 74LV00APW | -40 °C to +125 °C | TSSOP14 | plastic thin shrink small outline package; 14 leads; body width 4.4 mm | SOT402-1 | | | | |



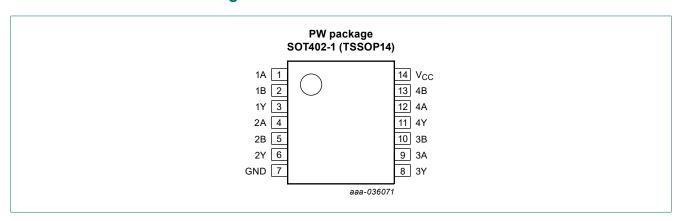
Quad 2-input NAND gate

4. Functional diagram



5. Pinning information

5.1. Pinning



5.2. Pin description

Table 2. Pin description

| Symbol | Pin | Description |
|-----------------|--------------|----------------|
| 1A, 2A, 3A, 4A | 1, 4, 9, 12 | data input |
| 1B, 2B, 3B, 4B | 2, 5, 10, 13 | data input |
| 1Y, 2Y, 3Y, 4Y | 3, 6, 8, 11 | data output |
| GND | 7 | ground (0 V) |
| V _{CC} | 14 | supply voltage |

Quad 2-input NAND gate

6. Functional description

Table 3. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = don't \ care.$

| Input | Output | |
|-------|--------|----|
| nA | nB | nY |
| L | X | Н |
| X | L | Н |
| Н | Н | L |

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|-------------------------|---|------------|------|-----------------------|------|
| V _{CC} | supply voltage | | | -0.5 | +7.0 | V |
| VI | input voltage | | [1] | -0.5 | +7.0 | V |
| Vo | output voltage | output HIGH or LOW state | [2] [3] | -0.5 | V _{CC} + 0.5 | V |
| | | output power-down | [2] | -0.5 | +7.0 | V |
| I _{IK} | input clamping current | V _I < 0 V | | -20 | - | mA |
| I _{OK} | output clamping current | V _O < 0 V | | -50 | - | mA |
| Io | output current | V _O = 0 V to V _{CC} | | - | ±35 | mA |
| I _{CC} | supply current | | | - | 70 | mA |
| I _{GND} | ground current | | | -70 | - | mA |
| T _{stg} | storage temperature | | | -65 | +150 | °C |
| P _{tot} | total power dissipation | T _{amb} = -40 °C to +125 °C | [4] | - | 500 | mW |

^[1] If the input current ratings are observed, the minimum input voltage ratings may be exceeded.

^[2] If the output current ratings are observed, the output voltage ratings may be exceeded.

^[3] This value is limited to 7 V maximum.

^[4] For SOT402-1 (TSSOP14) package: P_{tot} derates linearly with 7.3 mW/K above 81 °C.

Quad 2-input NAND gate

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------|-------------------------------------|----------------------------------|-----|-----|-----------------|------|
| V _{CC} | supply voltage | | 2.0 | 5.0 | 5.5 | V |
| VI | input voltage | | 0 | - | 5.5 | V |
| Vo | output voltage | output HIGH or LOW state | 0 | - | V _{CC} | V |
| | | output power-down | 0 | - | 5.5 | V |
| T _{amb} | ambient temperature | | -40 | +25 | +125 | °C |
| Δt/ΔV | input transition rise and fall rate | V _{CC} = 2.3 V to 2.7 V | - | - | 200 | ns/V |
| | | V _{CC} = 3.0 V to 3.6 V | - | - | 100 | ns/V |
| | | V _{CC} = 4.5 V to 5.5 V | - | - | 20 | ns/V |

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | 25 °C | | -40 °C to +85 °C | | -40 °C to +125 °C | | Unit | |
|------------------|------------------------------|---|----------------------|-----|--------------------|----------------------|--------------------|----------------------|--------------------|----|
| | | | Min | Тур | Max | Min | Max | Min | Max | |
| V_{IH} | HIGH-level | V _{CC} = 2 V | 1.5 | - | - | 1.5 | - | - | - | V |
| | input voltage | V _{CC} = 2.3 V to 2.7 V | 0.7V _{CC} | - | - | 0.7V _{CC} | - | - | - | V |
| | | V _{CC} = 3.0 V to 3.6 V | 0.7V _{CC} | - | - | 0.7V _{CC} | - | - | - | V |
| | | V _{CC} = 4.5 V to 5.5 V | 0.7V _{CC} | - | - | 0.7V _{CC} | - | - | - | V |
| V _{IL} | LOW-level | V _{CC} = 2 V | - | - | 0.5 | - | 0.5 | - | 0.5 | V |
| | input voltage | V _{CC} = 2.3 V to 2.7 V | - | - | 0.3V _{CC} | - | 0.3V _{CC} | - | 0.3V _{CC} | V |
| | | V _{CC} = 3.0 V to 3.6 V | - | - | 0.3V _{CC} | - | 0.3V _{CC} | - | 0.3V _{CC} | V |
| | | V _{CC} = 4.5 V to 5.5 V | - | - | 0.3V _{CC} | - | 0.3V _{CC} | - | 0.3V _{CC} | V |
| V _{OH} | HIGH-level | V _I = V _{IH} or V _{IL} | | | | | | | | |
| | output voltage | V _{CC} = 2.0 V to 5.5 V; I _O = -50 μA | V _{CC} -0.1 | - | - | V _{CC} -0.1 | - | V _{CC} -0.1 | - | V |
| | | V _{CC} = 2.3 V; I _O = -2 mA | 2 | - | - | 2 | - | 2 | - | V |
| | | V _{CC} = 3.0 V; I _O = -6 mA | 2.48 | - | - | 2.48 | - | 2.48 | - | V |
| | | V _{CC} = 4.5 V; I _O = -12 mA | 3.8 | - | - | 3.8 | - | 3.8 | - | V |
| V_{OL} | LOW-level | V _I = V _{IH} or V _{IL} | | | | | | | 1 | |
| | output voltage | V _{CC} = 2.0 V to 5.5 V; I _O = 50 μA | - | - | 0.1 | - | 0.1 | - | 0.1 | V |
| | | V _{CC} = 2.3 V; I _O = 2 mA | - | - | 0.4 | - | 0.4 | - | 0.4 | V |
| | | V _{CC} = 3.0 V; I _O = 6 mA | - | - | 0.44 | - | 0.44 | - | 0.44 | V |
| | | V _{CC} = 4.5 V; I _O = 12 mA | - | - | 0.55 | - | 0.55 | - | 0.55 | V |
| I _{OFF} | power-off leakage current | V_I or V_O = GND to 5.5 V; V_{CC} = 0 V | - | - | 0.5 | - | 5 | - | 5 | μΑ |
| l _l | input leakage current | $V_I = V_{CC}$ or GND; $V_{CC} = 0$ V to 5.5 V | - | - | ±0.1 | - | ±1 | - | ±1 | μΑ |
| I _{CC} | supply current | $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$ | - | - | 2 | - | 20 | - | 20 | μΑ |

Quad 2-input NAND gate

10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 5.

| Symbol | Parameter | Conditions | | 25 °C | | -40 °C to | o +85 °C | -40 °C to | +125 °C | Unit |
|-----------------|-----------------------|--|-----|--------|------|-----------|----------|-----------|---------|------|
| | | | Min | Typ[1] | Max | Min | Max | Min | Max | |
| t _{pd} | propagation | nA, nB to nY; see Fig. 4 [2] | | | | | | | | |
| | delay | V _{CC} = 2.3 V to 2.7 V | | | | | | | | |
| | | C _L = 15 pF | - | 5.7 | 12.9 | 1 | 15 | 1 | 16 | ns |
| | | C _L = 50 pF | - | 7.8 | 16.6 | 1 | 20 | 1 | 21 | ns |
| | | V _{CC} = 3.0 V to 3.6 V | | | | | | | | |
| | | C _L = 15 pF | - | 4.3 | 7.9 | 1 | 9.5 | 1 | 10.5 | ns |
| | | C _L = 50 pF | - | 6.1 | 11.4 | 1 | 13 | 1 | 14 | ns |
| | | V _{CC} = 4.5 V to 5.5 V | | | | | | | | |
| | | C _L = 15 pF | - | 3.4 | 5.5 | 1 | 6.5 | 1 | 7 | ns |
| | | C _L = 50 pF | - | 4.8 | 7.5 | 1 | 8.5 | 1 | 9 | ns |
| Cı | input capacitance | $V_I = V_{CC}$ or GND; $V_{CC} = 3.3 \text{ V}$ | - | 2 | 6 | - | 6 | - | 6 | pF |
| Co | output capacitance | $V_O = V_{CC}$ or GND; $V_{CC} = 3.3 \text{ V}$ | - | 5.6 | - | - | - | - | - | pF |
| C _{PD} | power dissipation | per buffer; $C_L = 50 \text{ pF}$; [3] f = 10 MHz; $V_I = \text{GND to } V_{CC}$ | | | | | | | | |
| | capacitance | V _{CC} = 3.3 V | - | 9.3 | - | - | - | - | - | pF |
| | | V _{CC} = 5.0 V | - | 9.5 | - | - | - | - | - | pF |

^[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 2.5 V, 3.3 V, and 5 V respectively, unless otherwise specified.

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$

Table 8. Noise characteristics at T_{amb} = 25 °C

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 5.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|------------------------------------|---|------|------|------|------|
| $V_{OL(p)}$ | LOW-level output voltage (peak) | $V_{CC} = 3.3 \text{ V}; C_L = 50 \text{ pF}$ | - | 0.2 | 0.8 | V |
| $V_{OL(v)}$ | LOW-level output voltage (valley) | $V_{CC} = 3.3 \text{ V}; C_L = 50 \text{ pF}$ | -0.8 | -0.1 | - | V |
| $V_{OH(v)}$ | HIGH-level output voltage (valley) | $V_{CC} = 3.3 \text{ V}; C_L = 50 \text{ pF}$ | - | 3.1 | - | V |
| $V_{IH(AC)}$ | AC HIGH-level input voltage | $V_{CC} = 3.3 \text{ V}; C_L = 50 \text{ pF}$ | 2.31 | - | - | V |
| $V_{\text{IL}(AC)}$ | AC LOW-level input voltage | V_{CC} = 3.3 V; C_L = 50 pF | - | - | 0.99 | V |

 t_{pd} is the same as t_{PLH} and t_{PHL} . C_{PD} is used to determine the dynamic power dissipation (P_D in μ W): $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

Quad 2-input NAND gate

10.1. Waveforms and test circuit

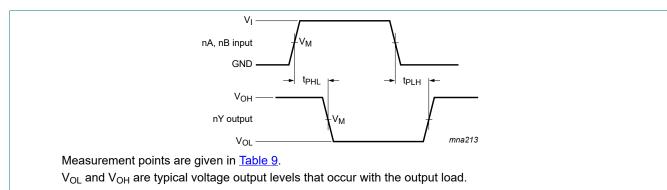


Fig. 4. Input (nA, nB) to output (nY) propagation delays

Table 9. Measurement points

| Input | Output |
|--------------------|--------------------|
| V_{M} | V _M |
| 0.5V _{CC} | 0.5V _{CC} |

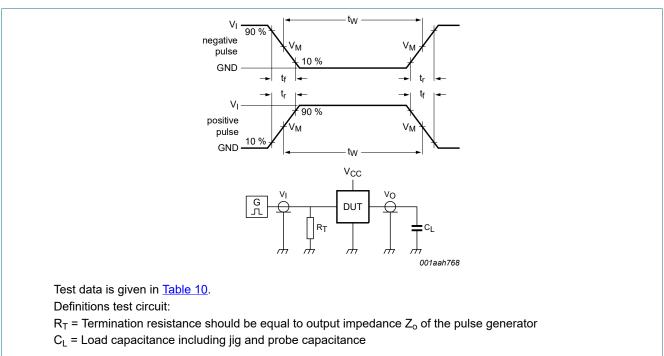


Fig. 5. Test circuit for measuring switching times

Table 10. Test data

| Input | | Load | Test |
|------------------------|---------------------------------|--------------|-------------------------------------|
| V _I | t _r , t _f | CL | |
| GND to V _{CC} | 3.0 ns | 15 pF, 50 pF | t _{PLH} , t _{PHL} |

Product data sheet

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11. Package outline

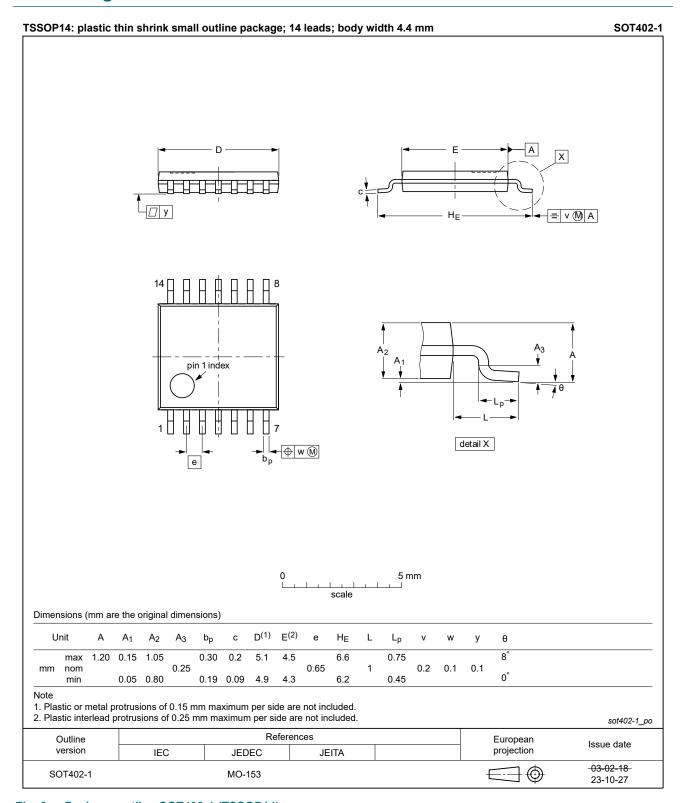


Fig. 6. Package outline SOT402-1 (TSSOP14)

Quad 2-input NAND gate

12. Abbreviations

Table 11. Abbreviations

| Acronym | Description |
|---------|-------------------------|
| CDM | Charge Device Model |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| НВМ | Human Body Model |

13. Revision history

Table 12. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | | |
|----------------|--|--------------------|---------------|-------------|--|--|
| 74LV00A v.3 | 20240129 | Product data sheet | - | 74LV00A v.2 | | |
| Modifications: | <u>Section 7</u>: Derating values for P_{tot} total power dissipation updated. <u>Fig. 6</u>: Aligned TSSOP package outline drawing to JEDEC MO-153 | | | | | |
| 74LV00A v.2 | 20231006 | Product data sheet | - | 74LV00A v.1 | | |
| Modifications | <u>Section 2</u> : ESD specification updated according to the latest JEDEC standard. | | | | | |
| 74LV00A v.1 | 20181219 | Product data sheet | - | - | | |

Quad 2-input NAND gate

14. Legal information

Data sheet status

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|--------------------------------|-----------------------|---|
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